NSN 5961-00-464-4127

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-464-4127 **Inclosure Material:** Metal **Overall Length:** 0.650 inches **Overall Height:** 0.070 inches **Overall Width:** 0.290 inches **Component Name And Quantity:** 2 transistor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 120.0 collector to base voltage, dc all transistor and 180.0 collector to emitter voltage/static/base open all transistor and 10.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 1200.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.4 watts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 300.0 small-signal short-circuit forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No